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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

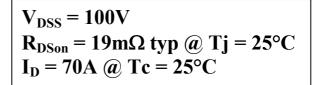


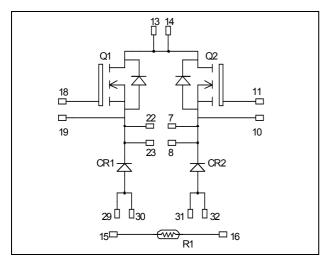


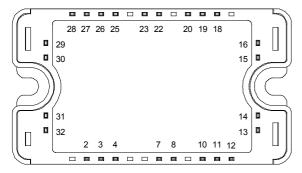




# Dual Buck chopper MOSFET Power Module







All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### **Features**

- Power MOS V® MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- RoHS Compliant

#### Absolute maximum ratings

Absolut	c maximum ratings			
Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
т.	Continuous Drain Current	$T_c = 25^{\circ}C$	70	
$I_{D}$	Continuous Drain Current	$T_c = 80$ °C	50	A
$I_{DM}$	Pulsed Drain current		300	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		21	mΩ
$P_{D}$	Maximum Power Dissipation	$T_c = 25^{\circ}C$	208	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		75	A
E <sub>AR</sub>	Repetitive Avalanche Energy		30	mJ
$E_{AS}$	Single Pulse Avalanche Energy		1500	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25$ °C			250	^
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			1000	μA
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 35A$	-		19	21	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 1 \text{mA}$		2		4	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	V			±100	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		5100		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		1900		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		800		
$Q_{g}$	Total gate Charge	$V_{GS} = 10V$		200		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 100V$		40		nC
$Q_{\text{gd}}$	Gate – Drain Charge	$I_D = 70A$		92		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		ns
$T_{r}$	Rise Time	$V_{GS} = 15V$		70		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 66V$ $I_{\text{D}} = 70A$		95		
$T_{\mathrm{f}}$	Fall Time	$R_G = 5\Omega$		125		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 66V$ $I_D = 70A$ , $R_G = 5\Omega$		276		т
$E_{\text{off}}$	Turn-off Switching Energy			302		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		304		T
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		320		μJ

### Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =200V	$T_j = 25$ °C			250	^
1 <sub>RM</sub>		V R−200 V	$T_j = 125$ °C			500	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		60		A
		$I_F = 60A$			1.1		
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 120A$			1.4		V
		$I_F = 60A$	$T_i = 125$ °C		0.9		
$t_{rr}$	Reverse Recovery Time	$I_F = 60A$ $V_R = 133V$	$T_j = 25$ °C		31		ns
·rr			$T_{j} = 125^{\circ}C$		60		115
Q <sub>rr</sub>	Reverse Recovery Charge	$di/dt = 200 A/\mu s$ $T_j =$	$T_j = 25$ °C		60		nC
			$T_{j} = 125^{\circ}C$		250		IIC



### Thermal and package characteristics

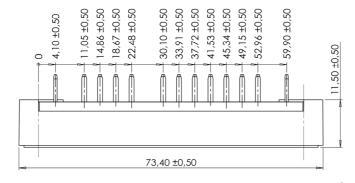
Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance  Transistor  Diode	Tran	sistor		0.6		°C/W
$R_{thJC}$		ode			0.9		
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		150	
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

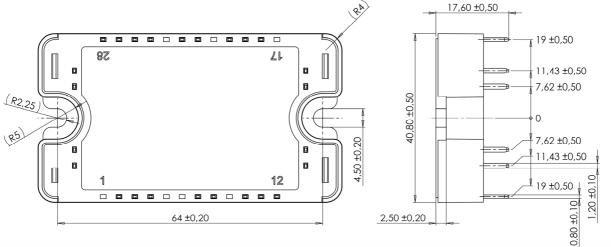
### Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_{T}: \text{ Thermistor value at T}$$

### SP3 Package outline (dimensions in mm)

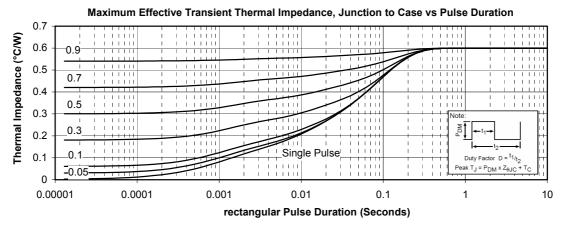


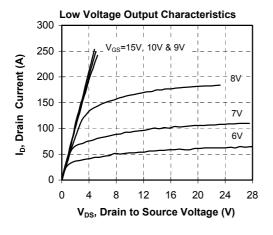


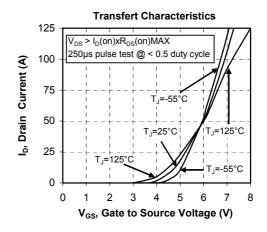
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

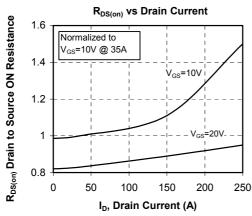


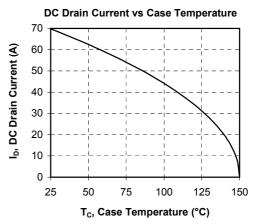
### **Typical Performance Curve**





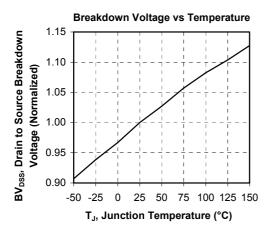


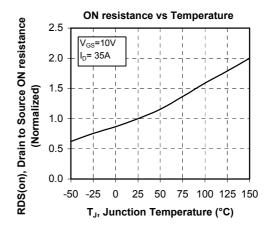


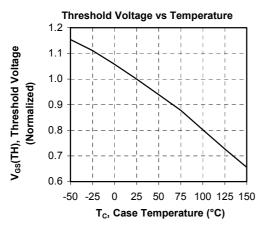


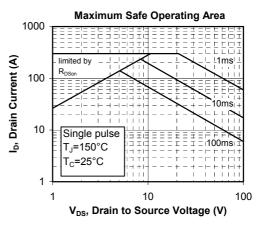
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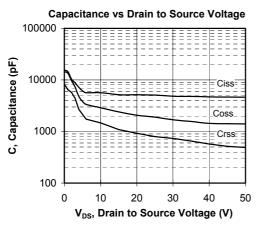


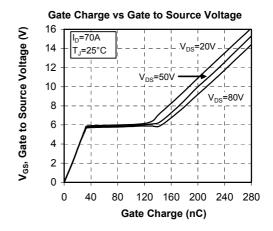




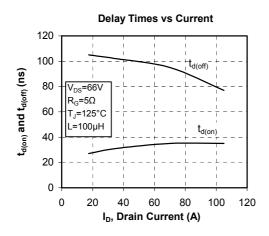


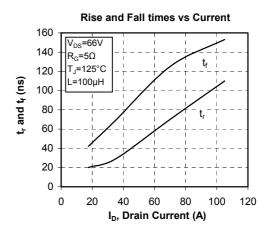


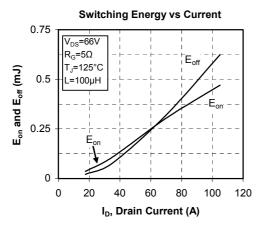


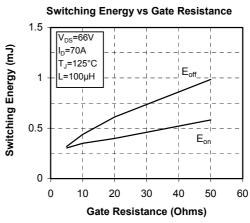


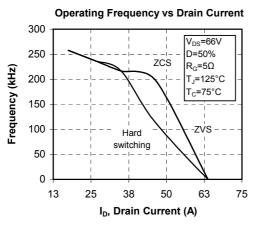


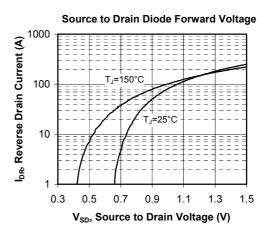












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